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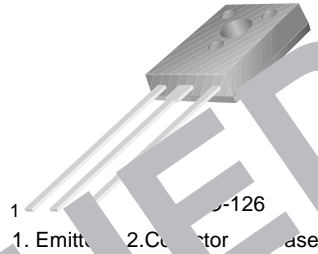
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KSC2752

KSC2752

**High Speed
High Voltage Switching Industrial Use**



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	500	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	7	V
I_C	Collector Current (DC)	0.5	A
I_{CP}	*Collector Current (Pulse)	1	A
I_B	Base Current (DC)	0.25	A
P_C	Collector Dissipation ($T_C=25^\circ\text{C}$)	10	W
P_C	Collector Dissipation (Pulsed)	10	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

* $PW \leq 300\mu\text{s}$, Duty Cycle $\leq 10\%$

Electric Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
$V_{CE0(sus)}$	Collector-Emitter Sustaining Voltage	$I_C = 0.3A, I_{B1} = -0.06A, L = 10mH$	400		V
$V_{CE0(sus)1}$	Collector-Emitter Sustaining Voltage	$I_C = 0.3A, I_{B1} = -I_{B2} = 0.06A, V_{BE(off)} = -5V, L = 10mH, \text{Clamped}$	450		V
$V_{CE0(sus)2}$	Collector-Emitter Sustaining Voltage	$I_C = 0.6A, I_{B1} = 0.2A, I_{B2} = -0.06A, V_{BE(off)} = -5V, L = 10mH, \text{Clamped}$	400		V
I_{CBO}	Collector Cut-off Current	$V_{CB} = 400V, I_E = 0$		10	μA
I_{CER}	Collector Cut-off Current	$V_{CE} = 400V, R_{BE} = 51\Omega, T_C = 125^\circ\text{C}$		1	mA
I_{CEX1}	Collector Cut-off Current	$V_{CE} = 400V, R_{BE(off)} = -1.5V$		10	μA
I_{CEX2}	Collector Cut-off Current	$V_{CE} = 400V, R_{BE(off)} = -1.5V @ T_C = 125^\circ\text{C}$		1	mA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_C = 0$		10	μA
h_{FE1}	* DC Current Gain	$V_{CE} = 5V, I_C = 0.05A$	20	80	
h_{FE2}		$V_{CE} = 5V, I_C = 0.3A$	10		
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage	$I_C = 0.3A, I_B = 0.06A$		1	V
$V_{BE(sat)}$	* Base-Emitter Saturation Voltage	$I_C = 0.3A, I_B = 0.06A$		2	V
t_{ON}	Turn ON Time	$V_{CC} = 150V, I_C = 0.3A$		1	μs
t_{STG}	Storage Time	$I_{B1} = -I_{B2} = 0.06A, R_L = 500\Omega$		2.5	μs
t_F	Fall Time	$PW = 50\mu\text{s}, \text{Duty Cycle} \leq 2\%$		1	μs

* Pulse Test: $PW \leq 350\mu\text{s}$, Duty Cycle $\leq 2\%$ Pulsed

h_{FE} Classification

Classification	R	O	Y
h_{FE1}	20 ~ 40	30 ~ 60	40 ~ 80

Typical Characteristics

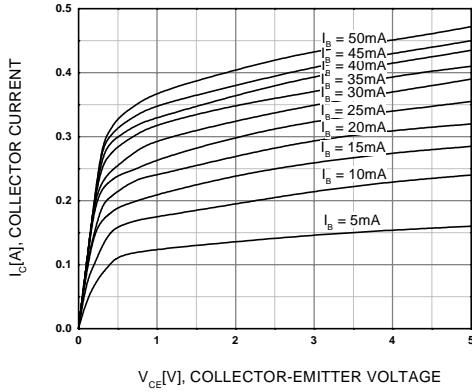


Figure 1. Static Characteristic

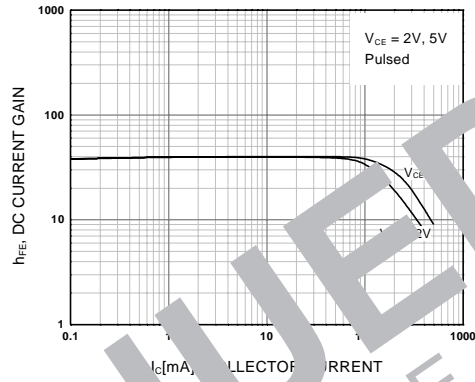


Figure 2. DC current gain

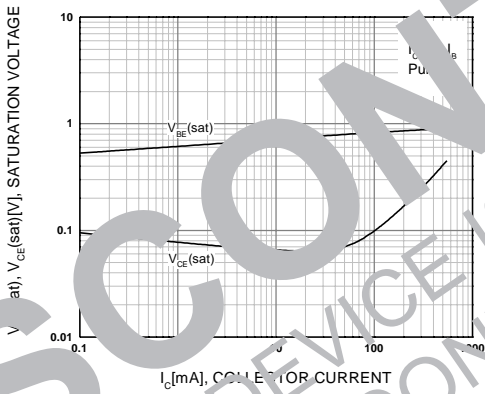


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

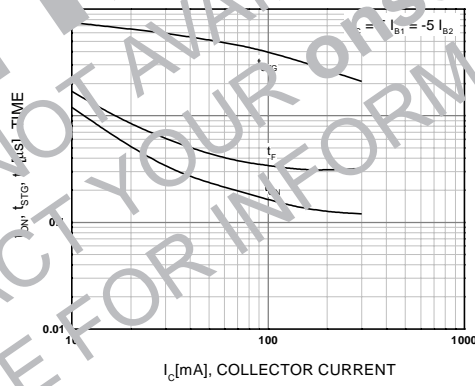


Figure 4. Switching Time

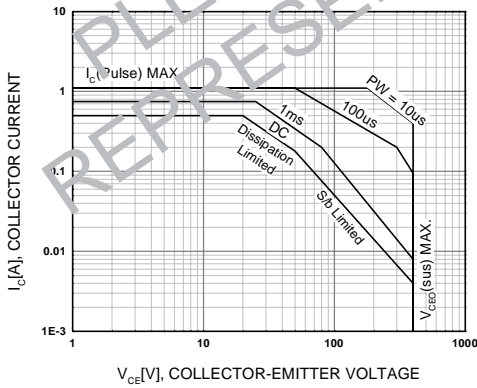


Figure 5. Safe Operating Area

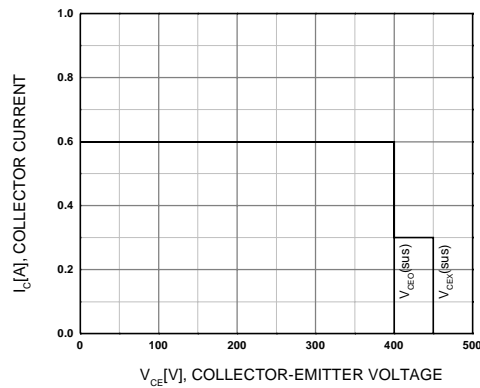


Figure 6. Reverse Bias Safe Operating Area

Typical Characteristics (Continued)

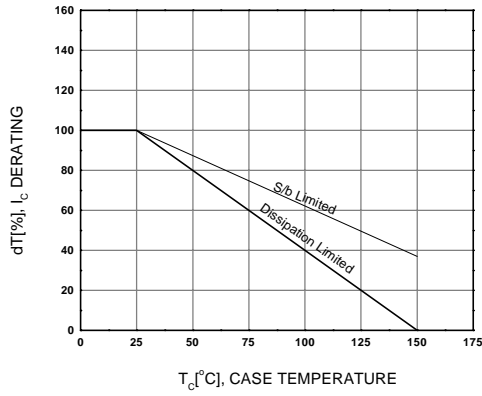


Figure 7. Derating Curve of Safe Operating Area

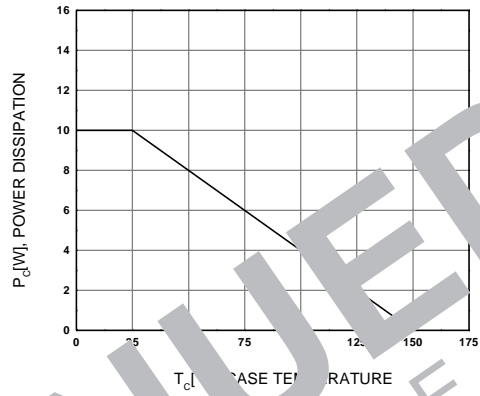
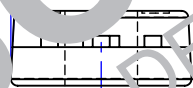
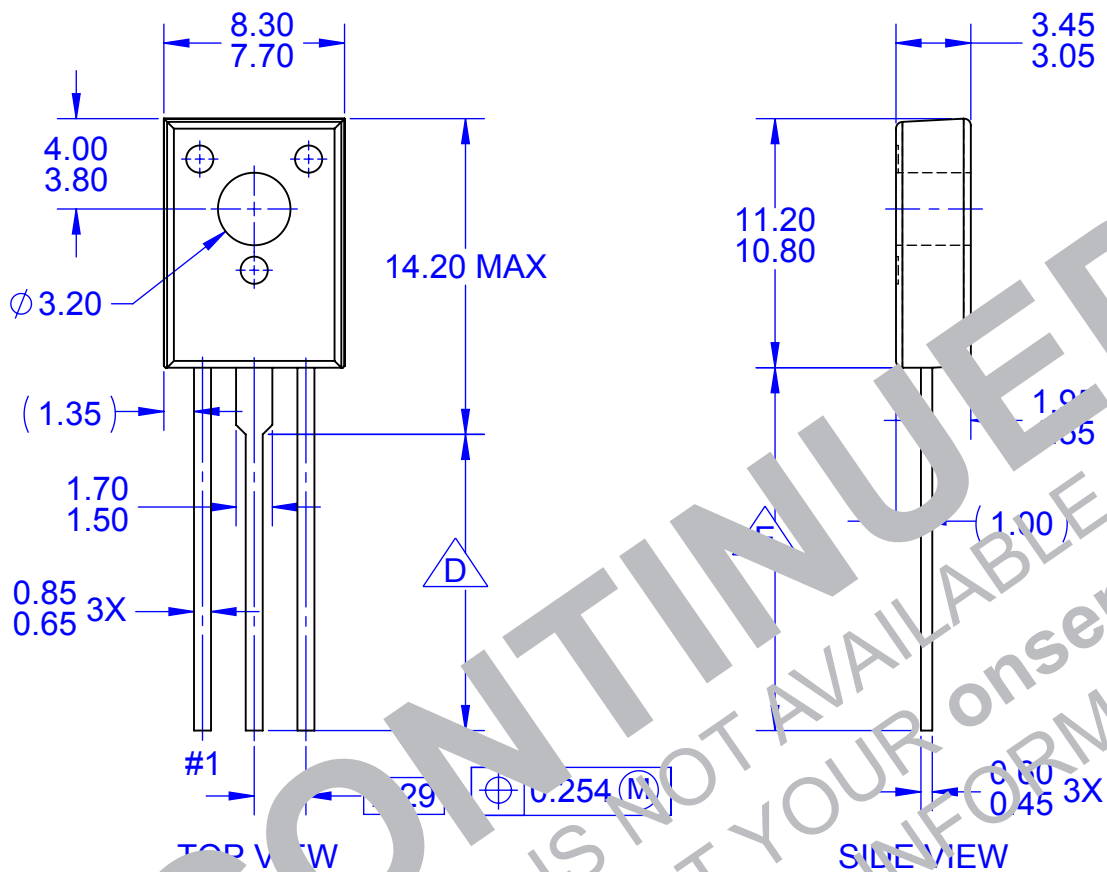


Figure 8. Power Derating

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FRONT VIEW

PRODUCTION CODE	TERMINAL LENGTH "D"	TERMINAL LENGTH "E"
TSSTU	3.45 - 4.05	6.45-7.45
TSTU	2.36 - 2.96	5.36-6.36
NONE (STD LENGTH)	12.76 - 13.36	15.76-16.76

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- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR PROTRUSIONS


FOR TERMINAL LENGTH "D", REFER TO TABLE

FOR TERMINAL LENGTH "E", REFER TO TABLE

F. DRAWING FILENAME: MKT-TO126Arev2



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